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**Gupta et al.**

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(54) **MEMS ELECTROSTATIC ACTUATOR**

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(2013.01); B81B 2203/058 (2013.01); B81B  
2203/06 (2013.01)

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B81B 2203/053; B81B 2203/058; B81B  
2203/06  
See application file for complete search history.

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U.S.C. 154(b) by 0 days.

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Sep. 13, 2012, now Pat. No. 9,040,854.

(60) Provisional application No. 61/606,041, filed on Mar.  
2, 2012, provisional application No. 61/534,157, filed  
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D. Cimino

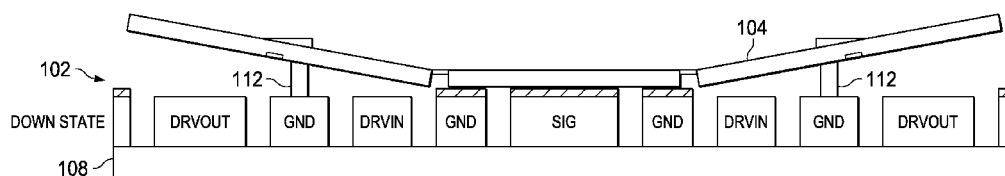
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CPC **H02N 2/12** (2013.01); **B81B 3/001** (2013.01);  
**B81B 3/0008** (2013.01); **B81B 3/0013**  
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(57) **ABSTRACT**

A MEMS electrostatic actuator includes a bottom plate  
affixed to a substrate and a top plate suspended above the  
bottom plate. The top plate has a parallel plate center section  
and two rotating members electrically connected to the center  
section. Each rotating member is attached centrally of the  
rotating member for rotation about an axis of rotation to a set  
of anchor posts. The attachment includes at least one pair of  
torsional springs attached along each axis, each spring com-  
prising a rectangular metal square that twists as the rotational  
members rotate. Electrostatic pull-down electrodes are  
underneath each rotational member.

**8 Claims, 15 Drawing Sheets**



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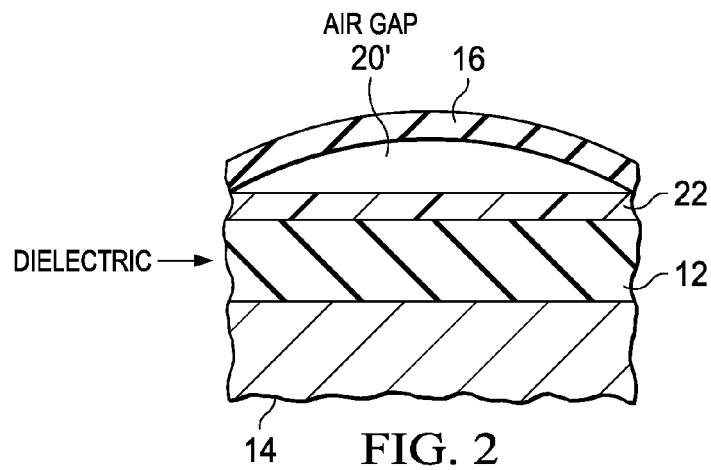
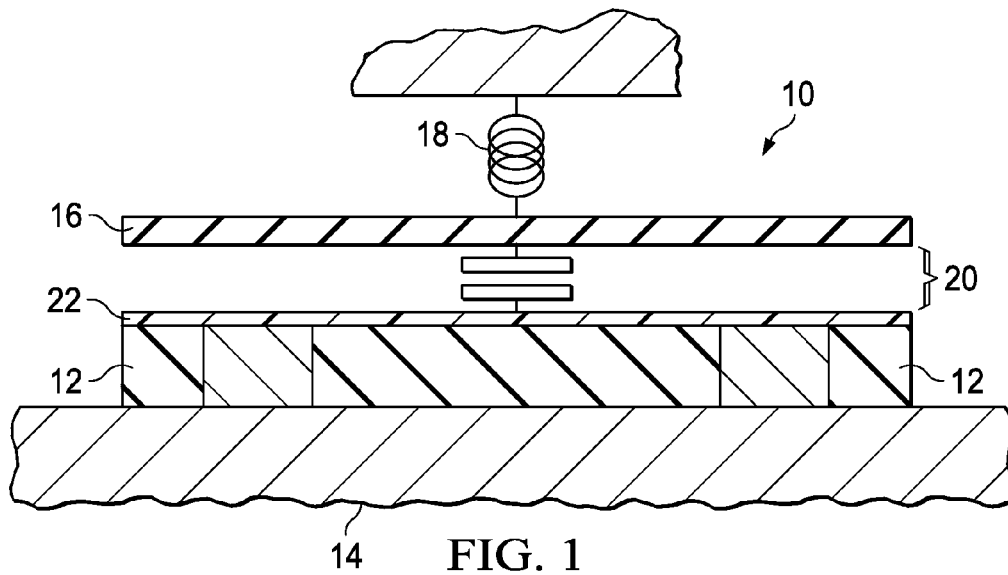
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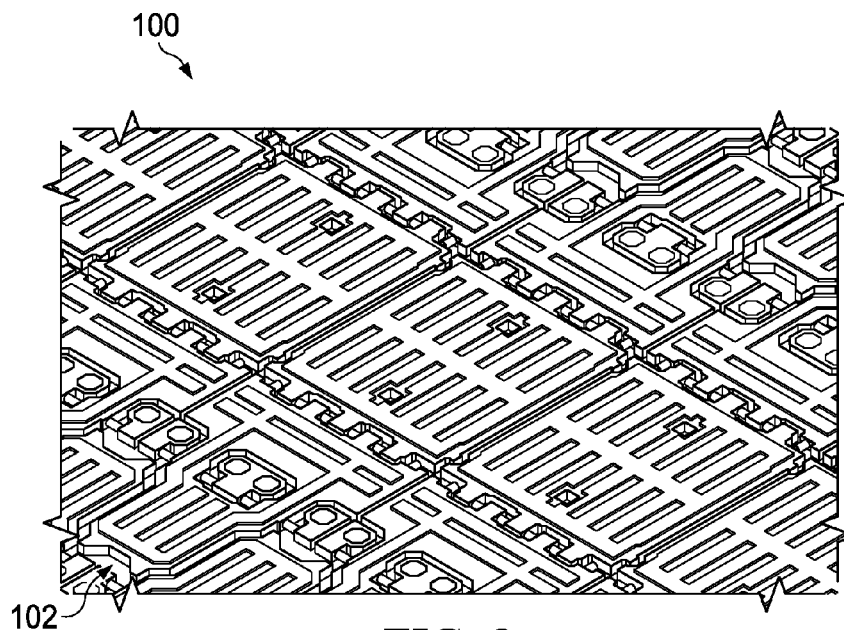


FIG. 3

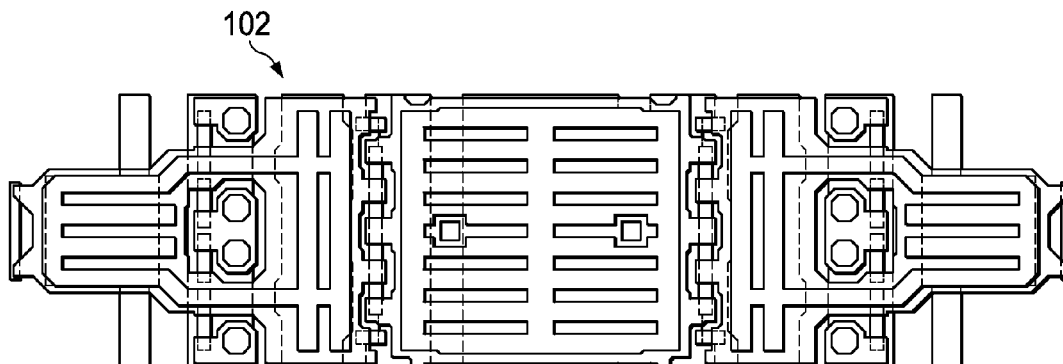
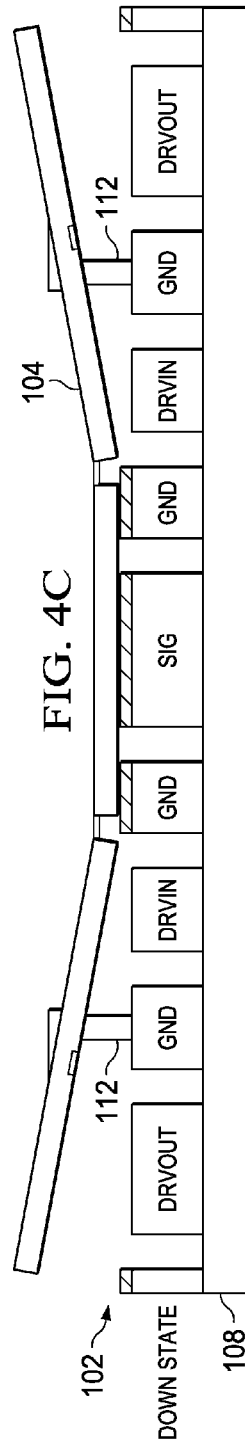
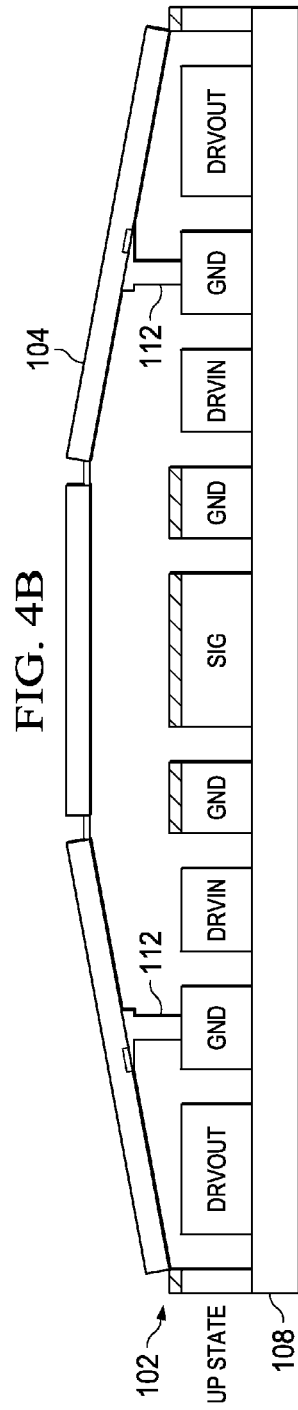
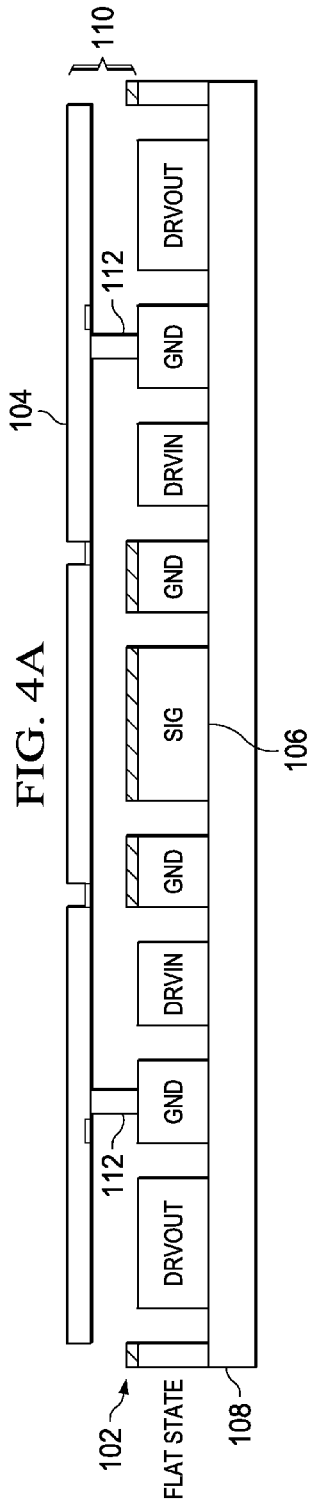


FIG. 5



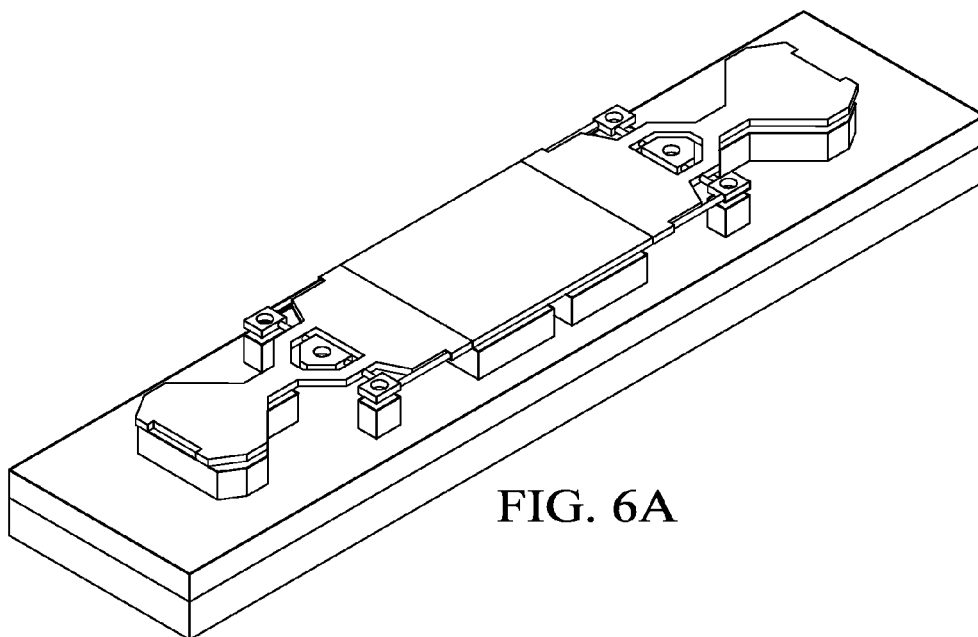


FIG. 6A

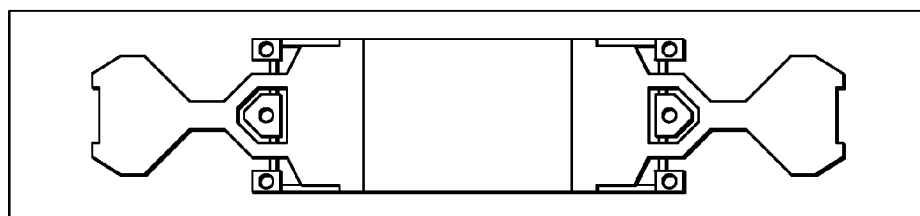


FIG. 6B

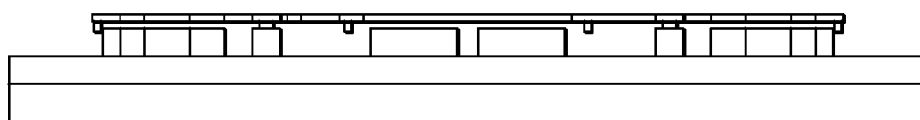


FIG. 6C

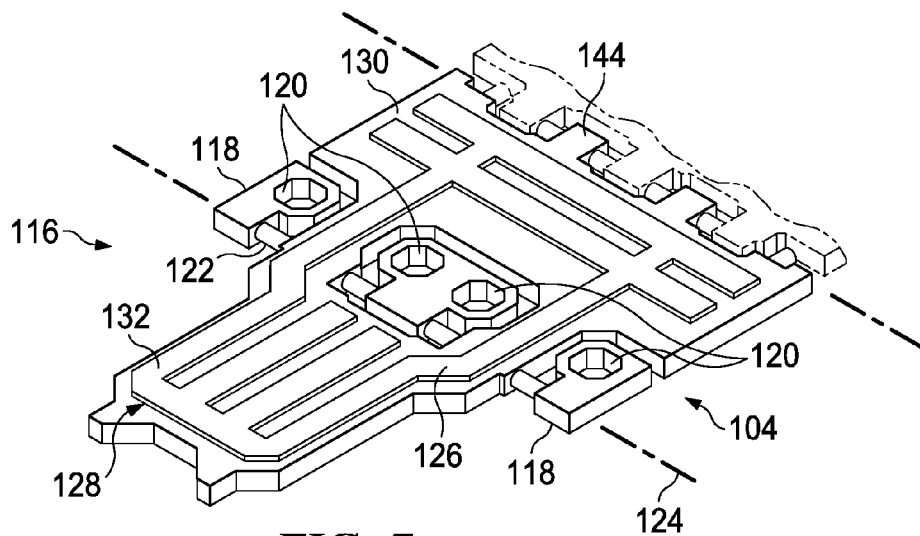


FIG. 7

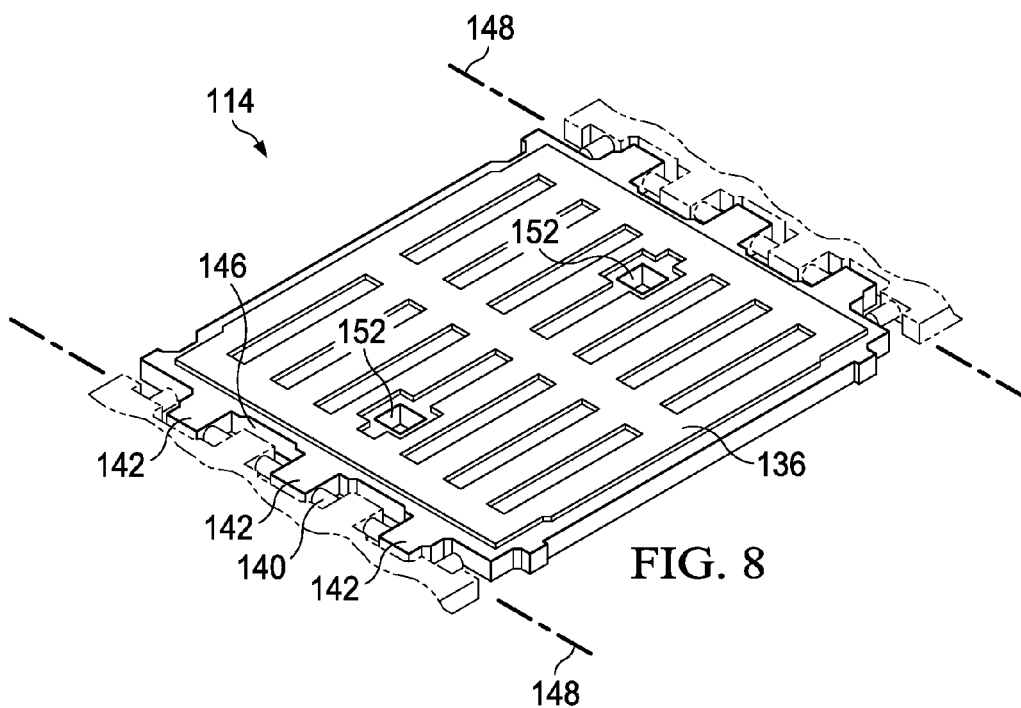


FIG. 8

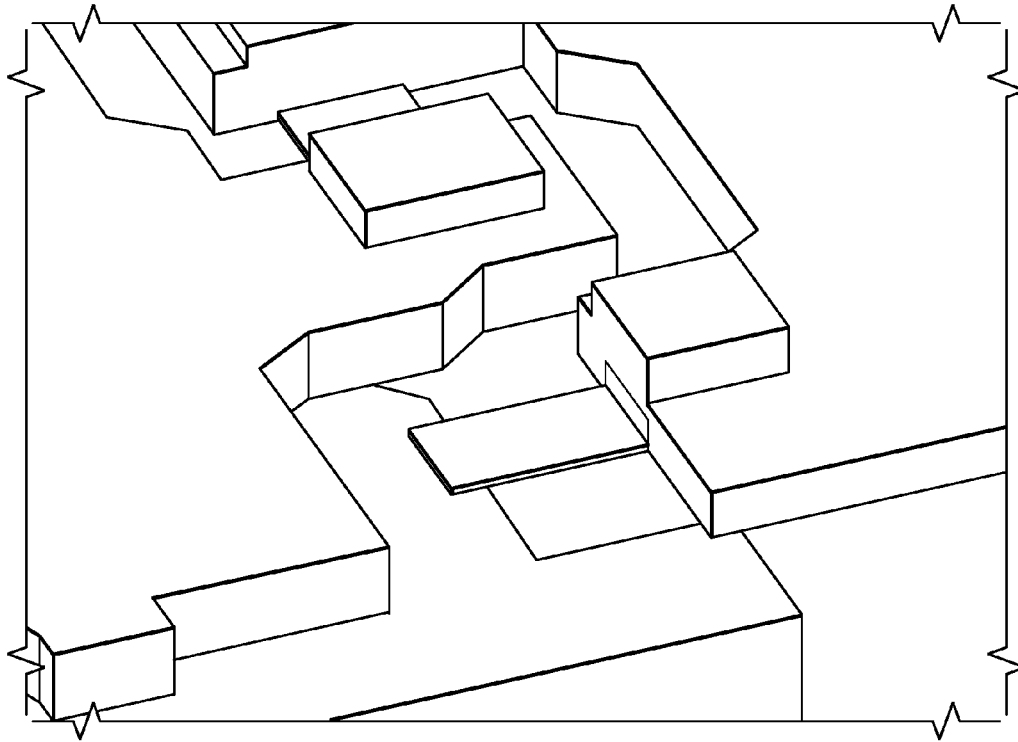


FIG. 9

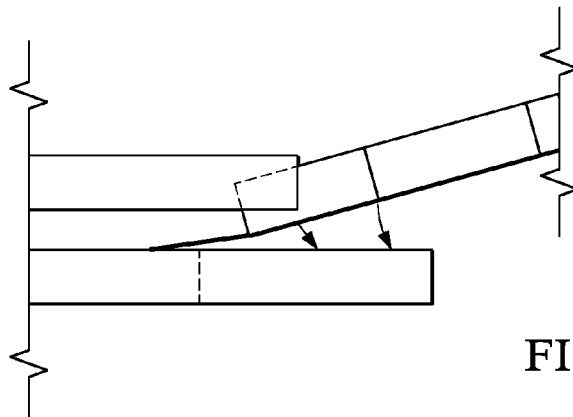
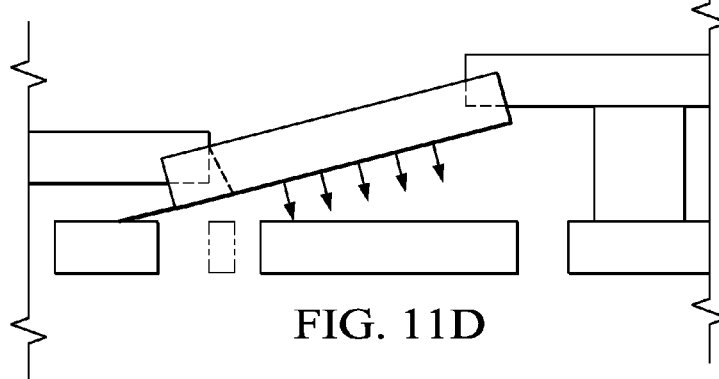
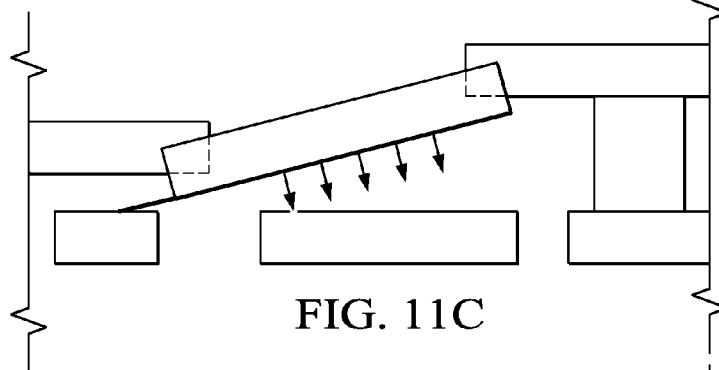
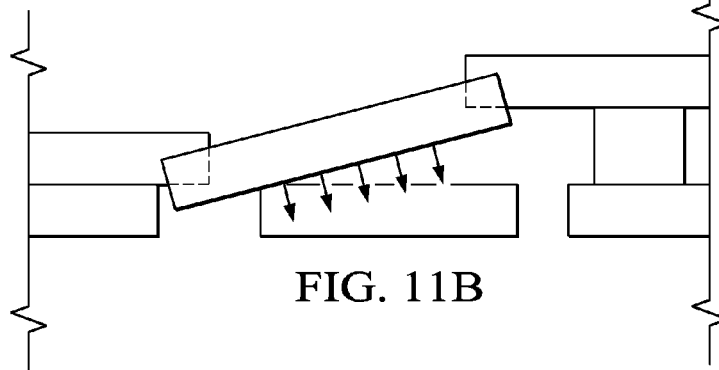
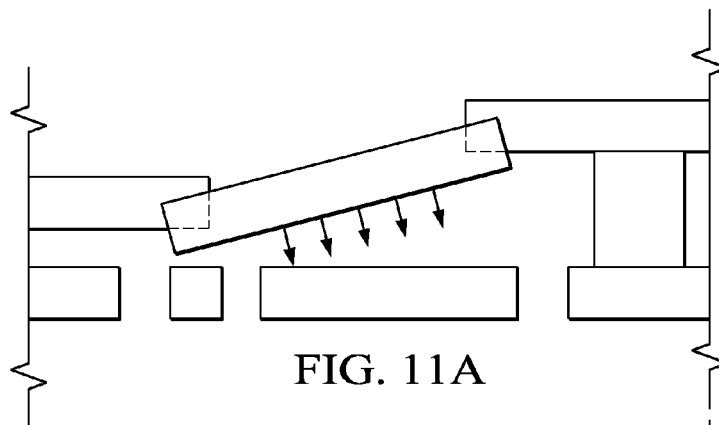


FIG. 10





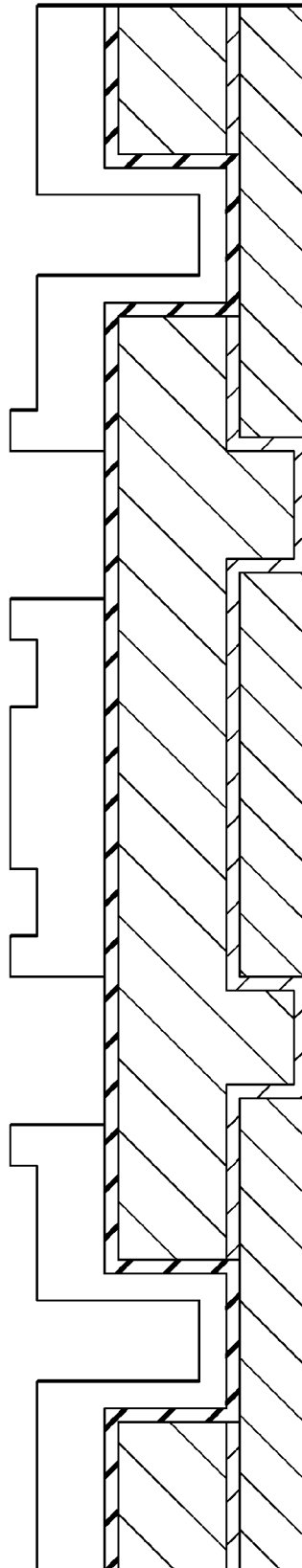


FIG. 12

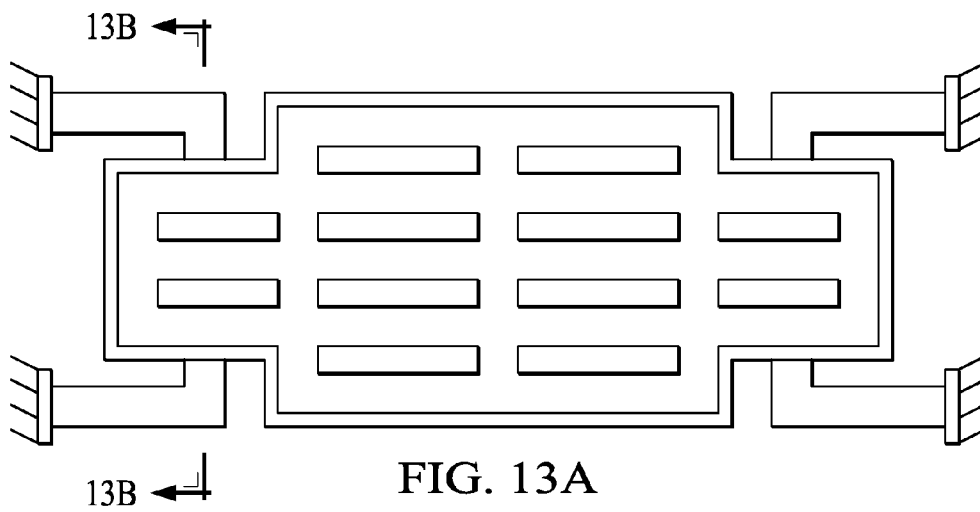


FIG. 13A

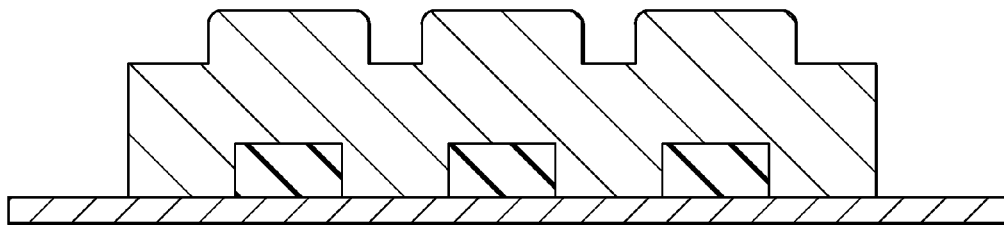


FIG. 13B

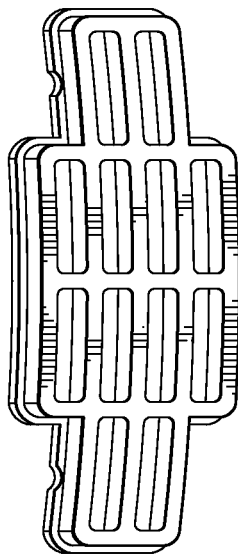


FIG. 14A

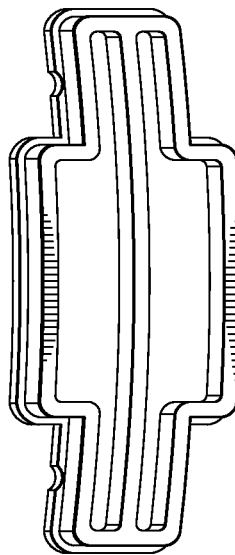


FIG. 14B

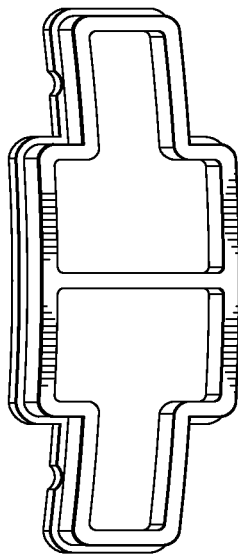


FIG. 14C

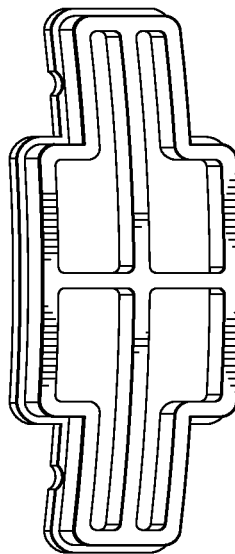


FIG. 14D

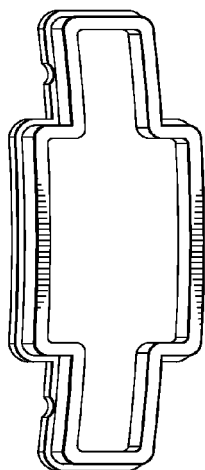


FIG. 14E

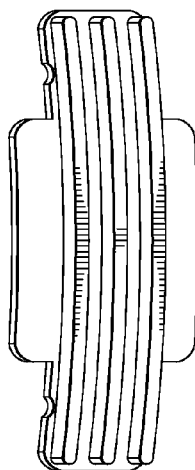


FIG. 14F

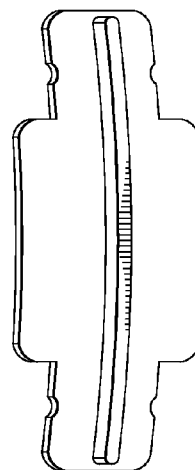


FIG. 14G

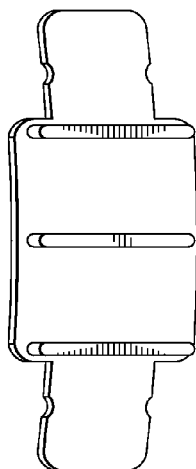


FIG. 14H

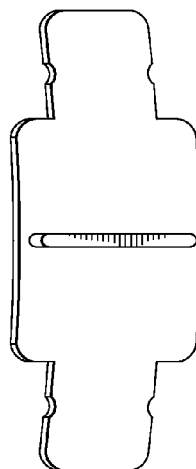


FIG. 14I

FIG. 15

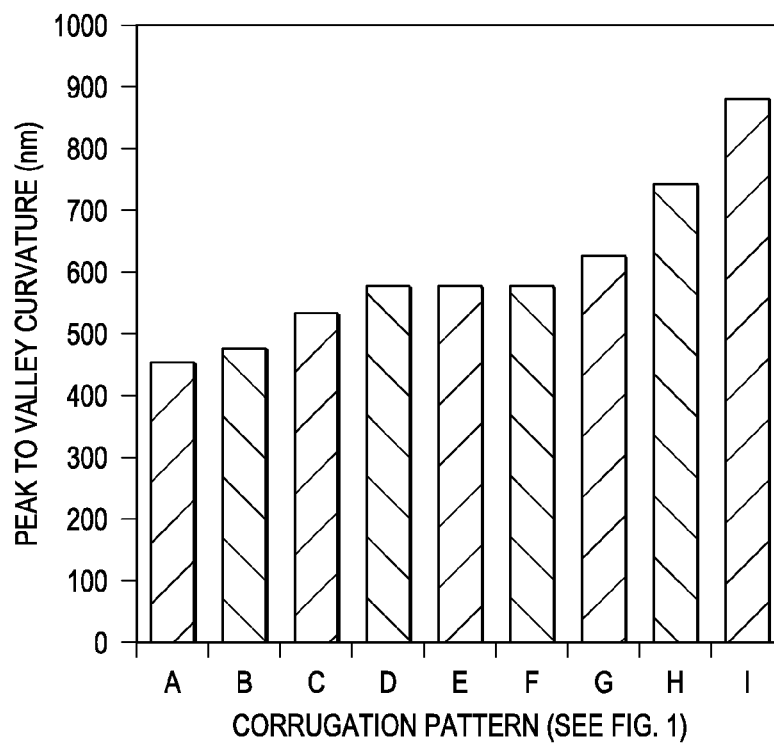
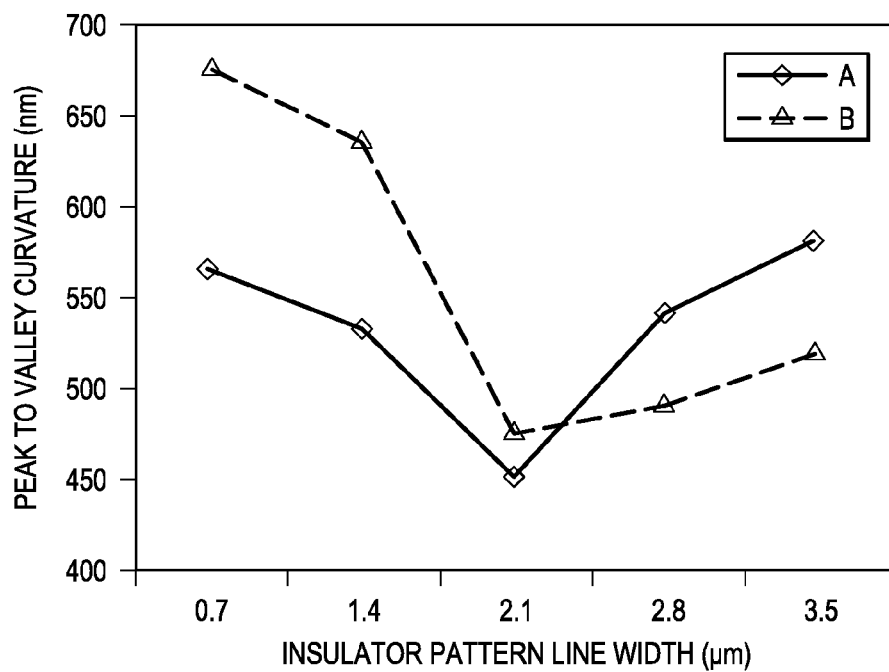


FIG. 16



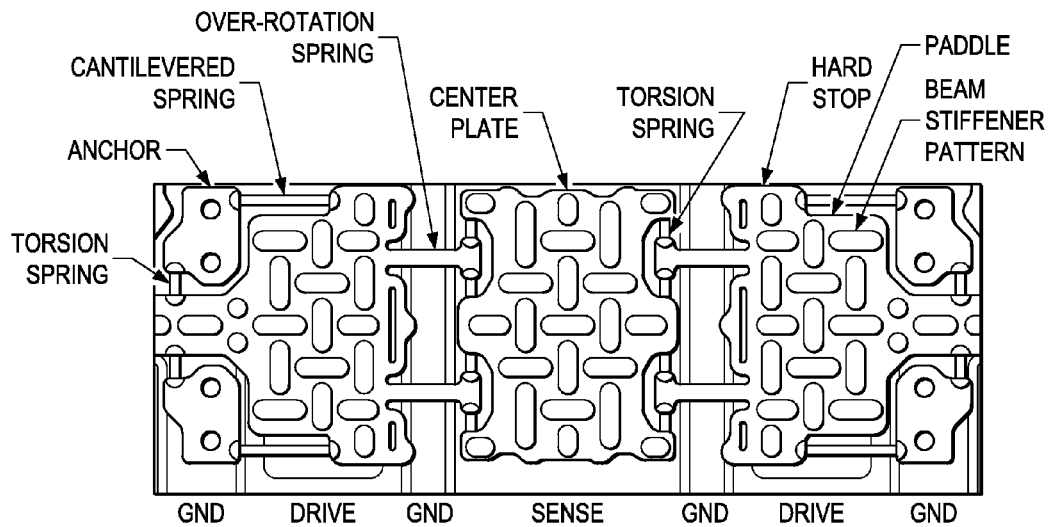


FIG. 17

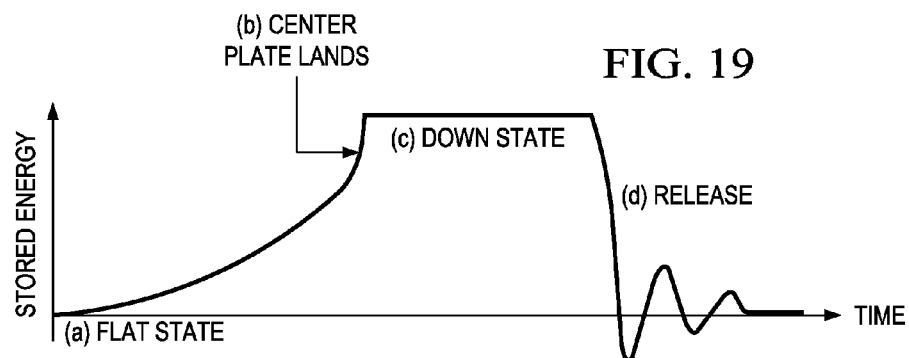


FIG. 19

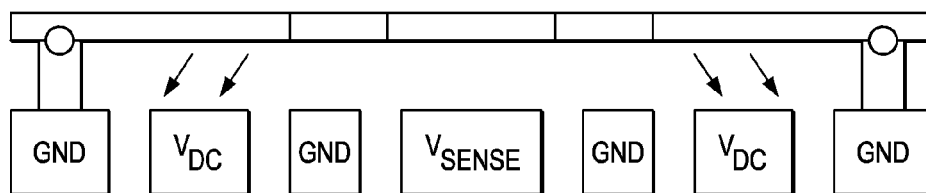


FIG. 18A

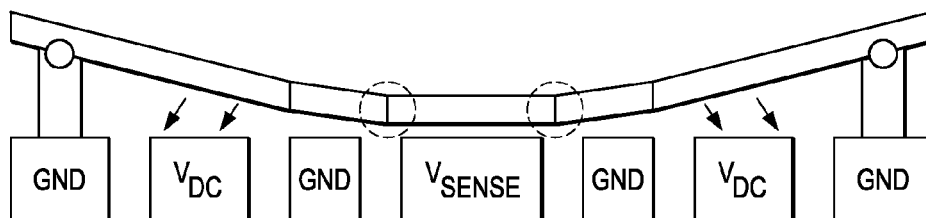


FIG. 18B

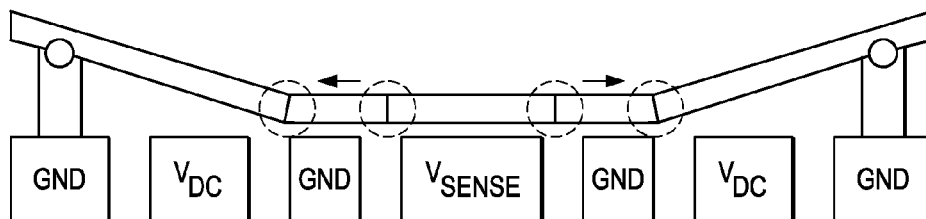


FIG. 18C

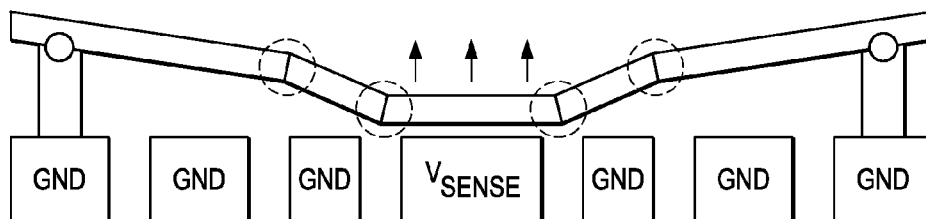


FIG. 18D



FIG. 20

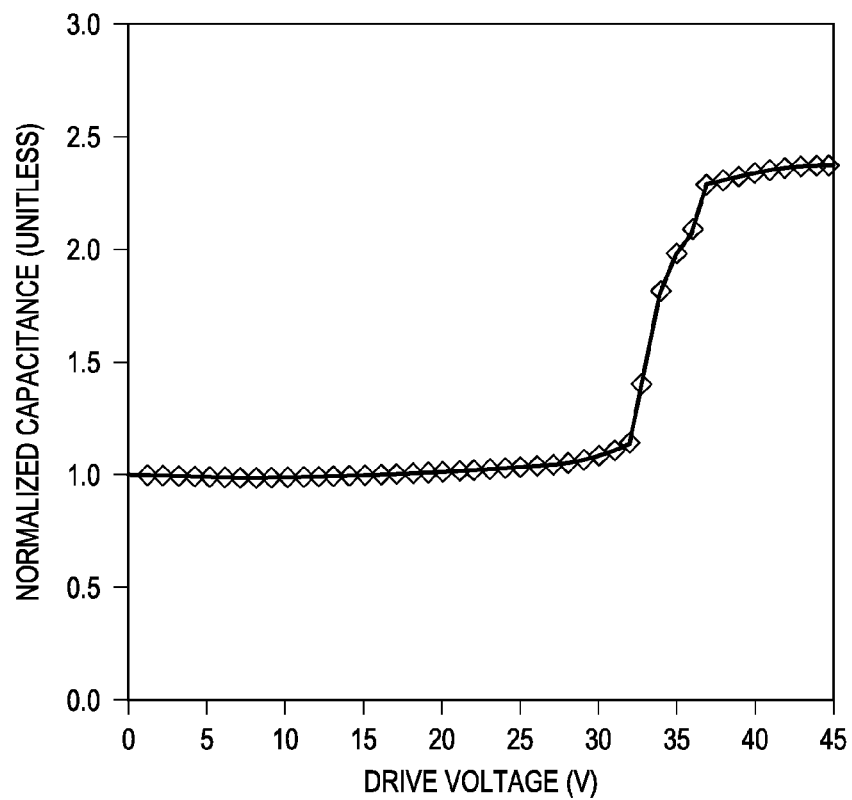
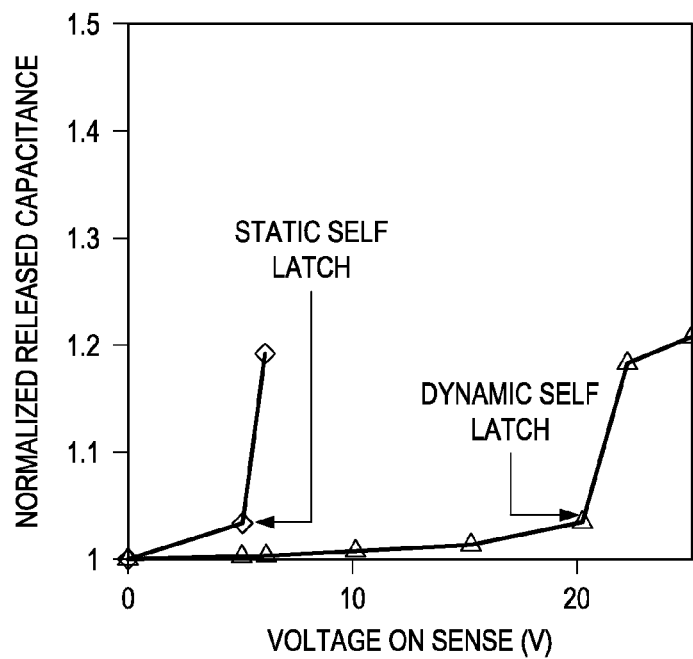


FIG. 21



## MEMS ELECTROSTATIC ACTUATOR

This application is a continuation of U.S. patent application Ser. No. 13/614,936 filed Sep. 13, 2012, which claims benefit of U.S. Provisional Application No. 61/606,041 filed Mar. 2, 2012, and U.S. Provisional Application No. 61/534,157 filed Sep. 13, 2011, the entireties of all of which are hereby incorporated herein by reference.

A MEMS electrostatic actuator and methods for its actuation are described.

## BACKGROUND

As shown schematically in FIG. 1, a MEMS electrostatic actuator **10** (also known as a capacitive actuator) generally comprises two parallel electrodes, one electrode (the “bottom plate”) **12** of which is typically fixed to a substrate **14** and the other electrode (the “top plate”) **16** of which is suspended with a spring suspension **18** spaced by an air gap **20** above the bottom plate. A thin solid dielectric film **22** is deposited on the surface of the bottom plate **12** to prevent shorting. A voltage is applied between the two electrodes, creating an electric field that produces an attractive force between the two electrodes **12**, **16**. This force causes displacement of the top plate **16**, until the top plate **16** makes contact with the dielectric **22** on the bottom plate **12**. Once the voltage is removed, the top plate **16** returns to its original position under the restorative force of spring suspension **18**.

A parallel plate actuator with a torsional architecture is described in P. Famelli, et al., “A Wide Tuning Range MEMS Varactor Based on a Toggle Push-Pull Mechanism,” Microwave Integrated Circuit Conference, 474-477 (2008), and in F. Solazzi, et al., “Active Recovering Mechanism for High Performance RF MEMS Redundancy Switches,” Proceedings of the 40<sup>th</sup> European Microwave Conference, 93-96 (September 2010), both of which are hereby incorporated herein by reference.

One problem that arises in connection with MEMS capacitive actuators is stiction—static friction associated with adhesion of contacting surfaces. Stiction occurs when Van der Waals forces and the like cause the top plate to stick down on the dielectric on the bottom plate, even after the actuation voltage is removed.

A second problem arises when the top plate is landed on the bottom plate. At this point, the electric field across the thin solid dielectric that separates the two plates is very high. This causes electrostatic charge to be injected into the dielectric, a phenomenon known as dielectric charging. The charged dielectric has its own contribution to the electric field between the two plates, and it can cause undesirable effects: It can change the release voltage, the voltage at which the top plate returns to its original position. It can change the land voltage, the voltage at which the top plate lands on the bottom plate. It can shift the voltage that produces minimum capacitance away from OV. These issues are problems for repeatability and reliability, and they can cause early device failure.

A third problem that arises when the device is used as a variable capacitor for RF applications is self-actuation. When RF energy is applied to the plates, the RMS voltage of the RF signal can cause the top plate to move and potentially even land on the bottom plate, even if there is no DC actuation voltage present. This is especially a problem in high power RF applications, as it limits the power-handling specification for the device.

A fourth problem, similar to self-actuation, is self-latching. In RF applications, when the top plate is landed on the bottom plate, the RMS voltage on the RF signal on the bottom plate

can hold the top plate down and prevent it from releasing, even when the DC actuation voltage is removed. This effectively prevents hot-switching, and presents a significant problem if the device is used in CDMA systems. The self-latching voltage is usually much lower than the self-actuation voltage.

A fifth problem is related to the flatness of the suspended top plate. Since the device is a parallel plate capacitor, both plates should ideally be flat and parallel. However, residual stresses from manufacturing can cause the top plate to curl. When the top plate is landed on the bottom plate, this curling creates an air gap between the two plates, greatly reducing on-state capacitance. This is illustrated in FIG. 2 which shows top plate **16** landed on solid dielectric layer **22** above bottom plate **12** on substrate **14**. Top plate **16** is curled downward making contact peripherally with dielectric **22** over bottom plate **12** and leaving an air gap **20'** centrally between the regions of contact.

Other problems are slow switching speed and slow actuator settling time upon release. When the DC actuation voltage is removed, the top plate moves upward due to the restoring force of its spring suspension. Generally, this mass-spring system is underdamped, causing oscillation. The problem arises when the settling time for the oscillation is longer than the maximum switching time of the system, for example in transmit/receive switching application for GSM mobile handsets.

Another problem is one of system integration. In a typical RF handset application, there is no high voltage power supply available. Adding an off-chip supply is highly undesirable due to cost and board real estate. Therefore, the DC actuation voltage must be supplied by on-chip circuitry. It is a manufacturing challenge to co-locate MEMS and CMOS components. RF CMOS processes may provide good RF performance, but may be cost prohibitive. Also, they may not have the right component set required to generate an on-chip electrostatic supply. On the other hand, standard mixed signal processes provide poor RF performance. Moreover, there is a limit to the magnitude of the voltage that can be generated on the chip. As such, the actuation voltage of the MEMS structure must be below that limit.

## SUMMARY

A MEMS electrostatic actuator and methods for its actuation are described that address the above-identified problems.

## BRIEF DESCRIPTION OF THE DRAWINGS

Example embodiments are described with reference to accompanying drawings, wherein:

FIG. 1 is a schematic representation of a parallel plate MEMS electrostatic actuator;

FIG. 2 is a schematic representation illustrating the problem of curling;

FIGS. 3-20 illustrate example embodiments, and

FIG. 21 shows static electrostatic hold down (5V) and dynamic holddown (20V) plots. Voltage is applied to the SENSE electrode in the down state, the varactor is released, and C is measured. In the dynamic test, the switching waveform on the DRIVE electrode has a fall time of <100 ns, while in the static test it is much slower.

## DESCRIPTION OF EXAMPLE EMBODIMENTS

An example MEMS structure **100** including a plurality of electrostatic actuators **102** is illustrated in FIG. 2. As shown in FIGS. 4A-4C, each actuator **102** has a first capacitor plate

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section **104** (the top plate) that is suspended above and a second capacitor plate section **106** (the bottom plate) that is affixed to a substrate **108**. The two sections **104**, **106** are separated by an air gap **110**, and the suspended section is supported by anchor vias **112**.

To address the problem of dielectric charging, the embodiment uses a torsional actuation. An articulated structure of a type suitable for torsional actuation is illustrated in commonly owned U.S. Pat. No. 8,171,804, incorporated herein by reference. The suspended portion **104** of the actuator is split up into three sections as illustrated in FIGS. 5-8: a parallel plate center section **114**, and two rotating paddle-shaped drive members **116**. All three sections **114**, **116** are electrically shorted to each other.

Each drive member **116** has anchor portions **118** attached to the substrate through a set of four anchor posts **112** at positions **120** (see FIG. 7) centrally of the drive member **116**. The anchor members **118** connect to remaining portions of the drive members through a torsion hinge member **122** which provides a horizontal axis of rotation **124** about which the drive member can pivot relative to the substrate **108**. The drive members **116** are disposed so that their respective axes **124** are parallel.

The main portion **126** of each drive member **116** is formed in a metal layer and including corrugations or raised portions **128** which provide rigidity to an otherwise generally planar, flat teeter-totter structure which pivots about the axis **124**. The main portion has inner and outer ends **130**, **132** laterally dimensioned with outer ends **132** having a smaller width dimension (direction parallel to axis **124**) than inner ends **132**, allowing like ends of drive members **116** of neighboring actuators **102** to be brought into interdigitated positions that enable staggered closer packing of pluralities of such structures (see FIG. 3). The wider inner ends **132** match a generally uniform width dimension of a corresponding plate section **114**.

The plate section **114** has a main section **136** of generally rectangular shape. It, too, is generally planar with the addition of undulations (corrugations or recesses) to impart rigidity (see FIG. 8). A width-wise extending pivot pin member **140** is provided at opposite ends of the main section **136**, traversing longitudinally directed tab extensions **142** formed at opposite ends of the main section **136**. Like tab extensions **144** (FIG. 7) formed at adjacent ends of the drive members **116** are disposed to extend into respective openings **146** between adjacent tab extensions **142** and contact the member **140**, allowing relative pivotal motion of the members **114**, **116** about horizontal axes **148**—parallel with the axes **124**—established by the members **140**. Openings **152** formed through the main section **136** provide release holes to prevent stiction when the main section **136** is in the actuated downward position.

The depicted actuator **102** has four parallel horizontal axes of rotation **124**, **148** enabling vertical movement of the main section **136** while keeping the planar section generally horizontal. As illustrated in FIGS. 6A-6C, one to two pairs of torsional springs are positioned along the axes, each consisting of a thin rectangular metal square that twists as the rotational members rotate.

As shown in FIGS. 4A-4C, electrostatic pull-in electrodes (i.e. drive electrodes) DRVIN are positioned on substrate **108** below inner portions **130** of drive members **116** between vias **112** and hinge members **122**. Electrostatic pull-out electrodes DRVOUT are positioned on substrate **108** below outer portions **132** of drive members **116** between vias **112** and the outermost portions (away from plate section **114**) of drive members **116**. The electrostatic electrodes act in pairs, with the inner set (DRVIN) acting together and the outer set

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(DRVOUT) acting together. When an electric potential difference is placed between the inner set of drive electrodes and the top plate, an electrostatic force is exerted on the top plate. This causes the two drive members **116** to rotate inwards about their respective axis **124** (toward the plate section **114**), which in turn causes the parallel center plate **114** to move downwards while remaining parallel to substrate **108**. As the potential difference increases, there will be a point at which the electrostatic force pulling the structure down becomes greater than the spring restoring force provided by the torsional springs. At this point, the top plate collapses down onto the dielectric layer formed over the bottom plate **106**. This is called pull-in and represents movement into the position shown in FIG. 4C.

In accordance with an aspect of the invention, the inner edge of each rotating member **116** includes thin rectangular protrusions known as “spring tips” extending longitudinally, laterally outward of and generally parallel with the tab extensions **144**. These spring tips extend inwardly beyond the inner edge of the rotating member. When pull-in occurs, the first parts of the suspended section to touch elements disposed on substrate **108** are the spring tips. These touch the GND electrodes shown in FIG. 4C which are located below the pivot pins **140**. The center plate **114** then lands on a thin dielectric layer covering the bottom plate **106** located below it. Plate **106** is illustrated by the signal electrode SIG shown in FIGS. 4A-4C. Plate **106** (i.e., SIG electrode) is covered with the thin dielectric layer to prevent electrical shorting. In the inwardly downward movement of drive members **116**, after the spring tips have made contact, hard stops in the form of rigid protrusions (hard stops) on the inner edges of the rotating drive members **116** next touch down on the GND electrodes, thereby preventing further rotation.

No portion of the rotating beams actually touches the biased drive electrodes. Since there is no direct electric contact and adequate air gap space between the drive electrodes and the three top plate segments, the field across the surface dielectric is greatly reduced. This greatly reduces oxide charging.

Furthermore, the device is designed to be bi-stable. The top plate can either be “pulled-in” or “pulled-out”. In pull-in, the DRVIN electrodes are biased, causing the rotational beams to rotate inward, and causing the parallel center beam to move downward. In pullout, the bias is removed from the DRVIN electrodes and applied to the DRVOUT electrodes. This causes the rotational beams to rotate outward, and the parallel center beam moves upward. There are hard stops in both the pull-in and pull-out cases, preventing over rotation and providing two mechanically stable states.

The top plate will return to a flat state (FIG. 4A) if bias is removed from all DRV electrodes. However, for the illustrated configuration the flat state may not be mechanically stable and achieving a flat state (no biasing) position may be influenced by residual charge in the surface dielectric, on the memory of the springs, and other phenomena. Further, in the absence of hard stops, the flat state may have a long settling time before reaching a steady state. For these reasons, the flat state is not utilized as a neutral position in operation of the illustrated device. (Of course, additional electrodes or other accommodation may be made if utilization of the flat state is desired.)

Switching directly between the pull-in and pull-out state solves several of the problems outlined above. First, it leads to fast switching speeds. Mechanical hard stops in both the up and down state mean that mechanical ringing is quickly damped out through the substrate. The device settles quickly and reaches a steady state much faster than it would if the flat

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state were used. Furthermore, since the device is electrostatically held in the up state, small amounts of residual charge in the dielectric on the DRVIN electrodes will not have an effect on the position or stability of the up state. Also, the pull-out state greatly increases self-actuation voltage. Since the device is actively held in the up state, it takes much more voltage on the SIG electrode to disturb the top plate when it is pulled out. Finally, the pull-out feature causes the parallel portion of the top plate to be pulled further away from the SIG electrode than it would otherwise be in the flat state. Since it is further away, any voltage on the SIG electrodes exerts less force on the top plate (since force is proportional to the inverse square of distance), further increasing the self-actuation voltage. The capacitance between the SIG electrode and the top plate in the up state is also reduced.

The stiction problem is addressed by several design features. First, stiction is a function of the area in which the top and bottom plates come into intimate contact. The surface of the bottom electrode is made very rough, with a peak-to-valley surface roughness around 800 Å. This roughness is achieved by making the bottom electrode 3 μm thick, allowing large grains to form in the metal. These grains produce surface roughness. The roughness limits the amount of area in which the top and bottom plates come into intimate contact, thereby reducing stiction.

A second design feature for stiction reduction is the inclusion of notches in the edges of the top and bottom plates. Stiction forces tend to be stronger along edges than along main surfaces. Thus, even if a main surface of the top plate releases off the bottom plate, one of the edges might still stick, causing the parallel center plate to become torqued at an angle. Adding small notched protrusions to the edges of the top and bottom plates greatly reduces the length of edge that could potentially stick.

A third design feature that helps with stiction is the addition of the spring tips, already mentioned. As these spring tips land, they deflect and thereby store energy. When the pull-in voltage bias is removed, the spring tips release the stored energy, helping the top plate to pop off the surface of the bottom plate. It is important to note that the force due to the pull-in voltage bias is much stronger when the two plates are close together compared to when they are far apart. Since the spring tips do not make contact and do not start deflecting until the top and bottom plates are brought close together, they can take advantage of the additional electrostatic force to store an extra "kick" of energy. This is similar to the energy storage capability of spring tips used to provide a restorative force in the deflection of micromirrors used in digital micromirror devices (DMDs).

A fourth design feature that helps with stiction is the use of torsional springs having high restoring force. Compared to an SPD DMD micromirror, the torsional springs in the described capacitive actuator are much shorter but with a similar thickness, leading to higher restoring force. There are also 4 to 8 pairs of torsional springs (one to two pairs along each of the four axes of rotation), compared to the single pair in a DMD micromirror. The total restoring provided by the torsional spring and spring tips in an implementation of the described actuator is 3-5 μN.

One of the consequences of high restoring force is that it may make the top plate difficult to pull down. The electrostatic pull-in force must typically be greater than the restoring force. The need for large pull-in force can be met by increasing the pull-in bias voltage, but it may be desirable to keep the bias voltage low so that it can be driven by on-chip CMOS circuitry. Therefore, increased pull-in force may instead be accomplished through use of large pull-down electrodes.

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Since the outer rotation axis acts as a fulcrum point, the further the pull-down electrode extends laterally away from the fulcrum, the larger the pull-down force will be. This is due to the multiplication of mechanical force provided by the lever that is formed by the fulcrum.

To take full advantage of the lever effect, it may be necessary to make the actuator very long. Long levers produce greater leverage than short levers. Long actuators may face two main problems, however: one is curling of the suspended top plate due to residual manufacturing stresses, and the other is reduced capacitance density since such a large area is occupied by the pull-down electrodes instead of the signal electrodes. The second problem is partially alleviated by making the outer portion of the actuator narrow, so that they the outer portions can be staggered and interleaved with adjacent actuators. This allows longer actuators with a higher overall capacitance density for the array.

Also, a low pull-down voltages (20V-30V) of the actuator is made possible because the torsional hinges are very thin but are manufactured with good uniformity across the wafer. The thinness of the hinge metal is accomplished through the use of a superstructure manufacturing flow used elsewhere in connection with DLP™ DMD devices. A DMD device fabrication process is described in M. Mignardi and R. Howell "The Fabrication of the Digital Micromirror Device," Commercialization of Microsystems '96 (1996), incorporated herein by reference.

Such manufacturing flow also allows the actuator to be built directly on top of the CMOS circuitry that drives it. However, standard CMOS is built on low resistivity substrates, which inherently result in high RF loss. This system-integration issue is resolved by including a solid metal ground shield between the CMOS and the variable capacitor. The ground shield isolates the RF energy from the substrate, so it does not experience high substrate loss. However, that ground shield adds unwanted parasitic capacitance that can reduce the capacitance ratio. To prevent this, a stack of thickened metals and thickened dielectrics can be used to increase physical distance between the variable capacitor and the ground shield. This extra distance reduces the parasitic capacitance of the ground shield.

The third and fourth design features that combat stiction also increase self-latch voltage. This is because both stiction and self-latch result from an attractive force between the top and bottom plates that tries to keep the top plate from pulling out. It is noted that the electrostatic force from RF energy on the SIG electrode varies with the inverse of the gap squared. Thus, even through the spring tips release their energy over only a short z-direction (vertical) distance, the self-latching force becomes significantly weaker over that distance, allowing the device to pull out.

The device can also benefit from the dynamic release of energy by the spring tips. Once the device is in the landed state, the spring tips can be further depressed and then released by pulsing the bias voltage on DRVIN. If this pulse matches the resonant frequency of the spring tips, the top plate will receive a resonant boost that amplifies the pull-out force by a factor of two to four times (2x-4x).

There are also design features intended to improve the planarity of the suspended beam. Firstly, the overall lateral dimensions of the actuator may be kept small (<100 μm). Residual stresses from manufacturing may add up over the length of the suspended beam, so a shorter beam may be less prone to stress-curling. Also, since the top plate may be suspended over 3 μm thick surface electrodes, the topology of the surface electrodes may be carried through the sacrificial layer up to the top plate. To prevent this, a planarization process can

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be employed in which the gaps between surface electrodes is filled with extra sacrificial material. That way the top plate can be deposited on a flat surface and avoid taking on the topology of the metal underneath it.

Furthermore, oxide ridges may be embedded into the suspended top plate. These oxide ridges provide added z-direction rigidity, allowing the actuator to resist curling due to residual stresses from manufacturing.

The suspended plate may be formed by first depositing a thin hinge material on top of a sacrificial layer. A hard oxide mask may then be deposited and patterned in order to define the torsional hinges and spring tips. A thick beam layer is then deposited and patterned to form the suspended plates. The pattern etch goes all the way down through the hinge layer, and the hard oxide mask protects the hinge from the etch in the areas where the torsional springs and spring tips are to be defined. The oxide mask is then stripped. However, in order to produce oxide ridges, the hard oxide mask is left embedded within the beam in corrugation patterns designed to give maximum z-direction rigidity. This produces a hinge-oxide-beam sandwich, where the beam completely covers the oxide ridges and protects them from the oxide strip process. Etch holes are also included in the beam for proper undercut (removal of sacrificial layer).

Those skilled in the art to which the invention relates will appreciate that the disclosed example embodiments may be modified and also that many other embodiments are possible within the scope of the claimed invention.

What is claimed is:

1. A MEMS electrostatic actuator device comprising an array of MEMS actuators, each MEMS actuator comprising:
  - a bottom plate affixed to a substrate, wherein the bottom plate is a signal electrode;
  - a top plate suspended above the bottom plate; the top plate comprising a parallel plate center section and two rotating drive members electrically connected to the center section, wherein the center section has openings to reduce stiction;
  - each rotating drive member is attached to a set of anchor posts, wherein the rotating drive members enable vertical movement of the center section; and
  - electrostatic pull-down electrodes underneath each rotating drive member.
2. The MEMS electrostatic actuator device of claim 1, wherein the rotating drive members have an outer end width

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that is less than an inner end width so that MEMS actuators of the array of MEMS actuators may be interdigitated.

3. The MEMS electrostatic actuator device of claim 1, wherein the parallel plate center section includes undulations to impart rigidity.

4. The MEMS electrostatic actuator device of claim 1, wherein the rotating drive members include spring tips at an end of each rotating member.

5. The MEMS electrostatic actuator device of claim 1, wherein the bottom plate has a rough surface due to large grains formed in a metal of the bottom plate.

6. The MEMS electrostatic actuator device of claim 5, wherein the bottom plate has a peak-to-valley surface roughness of around 800 Å.

7. The MEMS electrostatic actuator device of claim 1, wherein the top plate has notches at the edges of the parallel plate center section.

8. A MEMS electrostatic actuator device comprising an array of MEMS actuators, each MEMS actuator comprising:

- a bottom plate affixed to a substrate, wherein the bottom plate is a signal electrode;

- a top plate above the bottom plate, the top plate comprising a parallel plate center section and two rotating drive members electrically connected to the center section, wherein the center section has openings to reduce stiction;

- each rotating drive member is attached centrally of the rotating member for rotation about an axis of rotation to a set of anchor posts; the attachment including at least one pair of springs attached along each axis, each spring comprising a rectangular metal square that twists as the rotating drive members rotate;

- the rotating drive members including spring tips at inner ends;

- the rotating drive members having an outer end width that is less than an inner end width wherein the MEMS actuators of the array of MEMS actuators are interdigitated;

- the parallel plate center section having notches at edges adjacent the rotating drive members;

- a pivot pin member traversing the notches allowing relative pivotal motion of rotating drive members; and
- electrostatic pull-down electrodes underneath each rotating drive member.

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